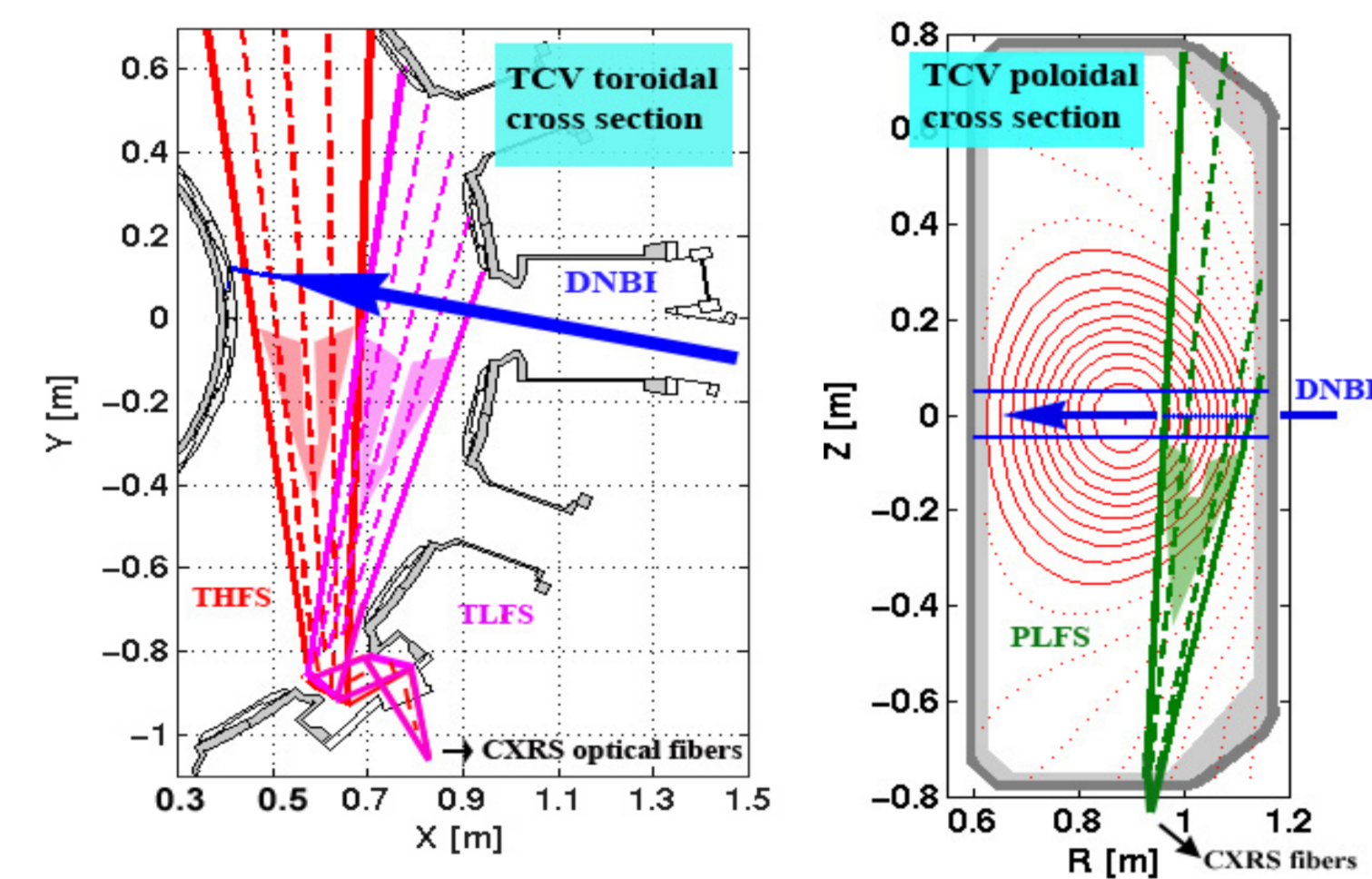


I. Introduction - outline

- v_ϕ and v_{pol} are measured with eITBs for the first time on TCV
- Effects of ECH power, co-/cnt-CD and MHD activity on the barrier strength, v , E_r and $\omega'_{E \times B}$ profiles are presented
- $E \times B$ shearing is not the cause of eITBs (confirms main role of reverse q profile for electron heating)
- E_r proportional to ∇p_i and $\hat{\omega}$
- Upgraded CXRS diagnostic on TCV with increased sensitivity and time resolution enables acquisitions near fast events

II. CXRS diagnostic on TCV

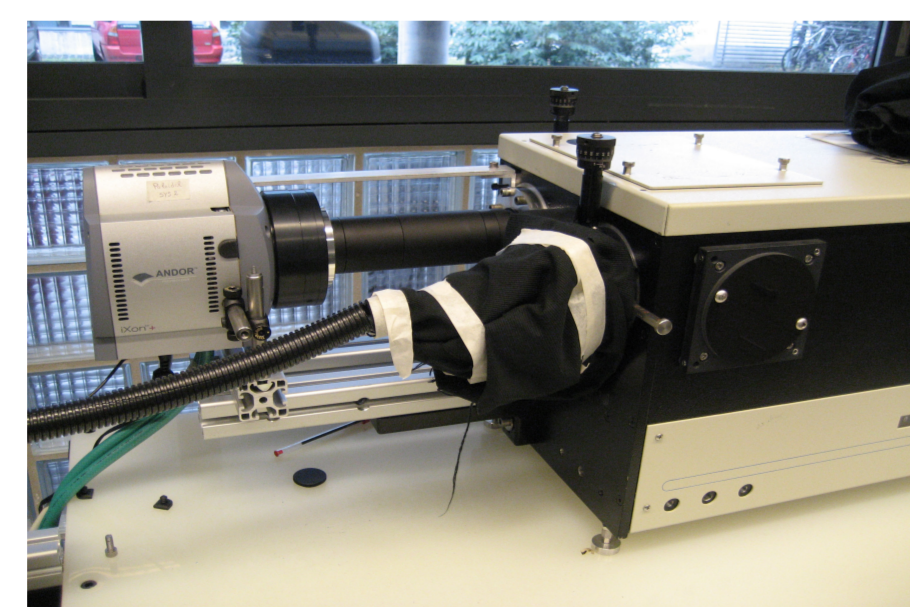
- TCV is equipped with a Charge eXchange Recombination Spectroscopy (CXRS) diagnostic
- CX reaction: C^{6+} (plasma) + neutral H^0 (low power Diagnostic Neutral Beam Injector, DNBI) \Rightarrow CVI line ($n=8 \rightarrow 7$, $\lambda = 529.1$ nm)
- Carbon main impurity in TCV (C wall) \rightarrow thermalised with main ion species (D or H)
- Collected light spectroscopically analysed $\rightarrow T_i, n_C, v_\phi$ and v_{pol} (v_θ) profiles of C ions along the vessel mid-plane
- DNBI injects 50 keV- H^0 atoms in 10-30 ms bursts at $z=0$ cm (Act./Pas.: 5-100%)



- 3 CXRS observation systems covering the plasma core and edge:
 - Toroidal Low Field Side (TLFS)
 - Toroidal High Field Side (THFS)
 - Poloidal Low Field Side (PLFS)
- 3 x 40 observation chords arranged in pairs (Double Slit configuration)
- Toroidal systems radial resolution of ~ 1.5 cm
- Standard Acquisition: $t_{int} = 10-30$ ms \rightarrow $t_{resolution} = 20-90$ ms
- Plasmas vertically centered around $z=0$ cm

III. CXRS present state (2011-2012 upgrade)

- Installed 2 Andor TM iXon $EM+$ DU897D-CSO-BV cameras
- Back illuminated e2v CCD97 detectors with Electron Multiplying (EM) gain up to 300
- Pre-Amplifier Gain: $\times 1 - \times 5$
- CCD image area $8.2 \times 8.2 mm^2$ with $16 \mu m$ pixel size
- Quantum efficiency: 95 %
- Frame transfer time: 0.25 ms
- Integration time in 512 x 20 frame transfer format: 1.7 ms



- Improved time resolution: 40 chords full range acquisition less than 2 ms!
- Increased sensitivity: $\times 8$ better S/N ratio!
 - TCV: low power DNBI perturbs only slightly the plasma (externally applied torque neglected)
 - $v_\phi =$ intrinsic ion rotation (ITER like)
 - Beam traverses the whole plasma BUT limited active signal intensity!
 - Other devices: high power NBI perturbs v_ϕ profiles dominated by applied torque

- Standard triggering:
 - CXRS acquisition synchronized with DNBI pulses (ramp up triggering)
 - Real Time (RT) - control sawteeth (ST) trigger modulation to stabilise ST frequency
- Enlarged CXRS exploitation: detect faster events (\sim few ms) in scenarios where beam strongly attenuated and active signal weaker or much more irregular (eITBs or n_e ramp in H-modes)

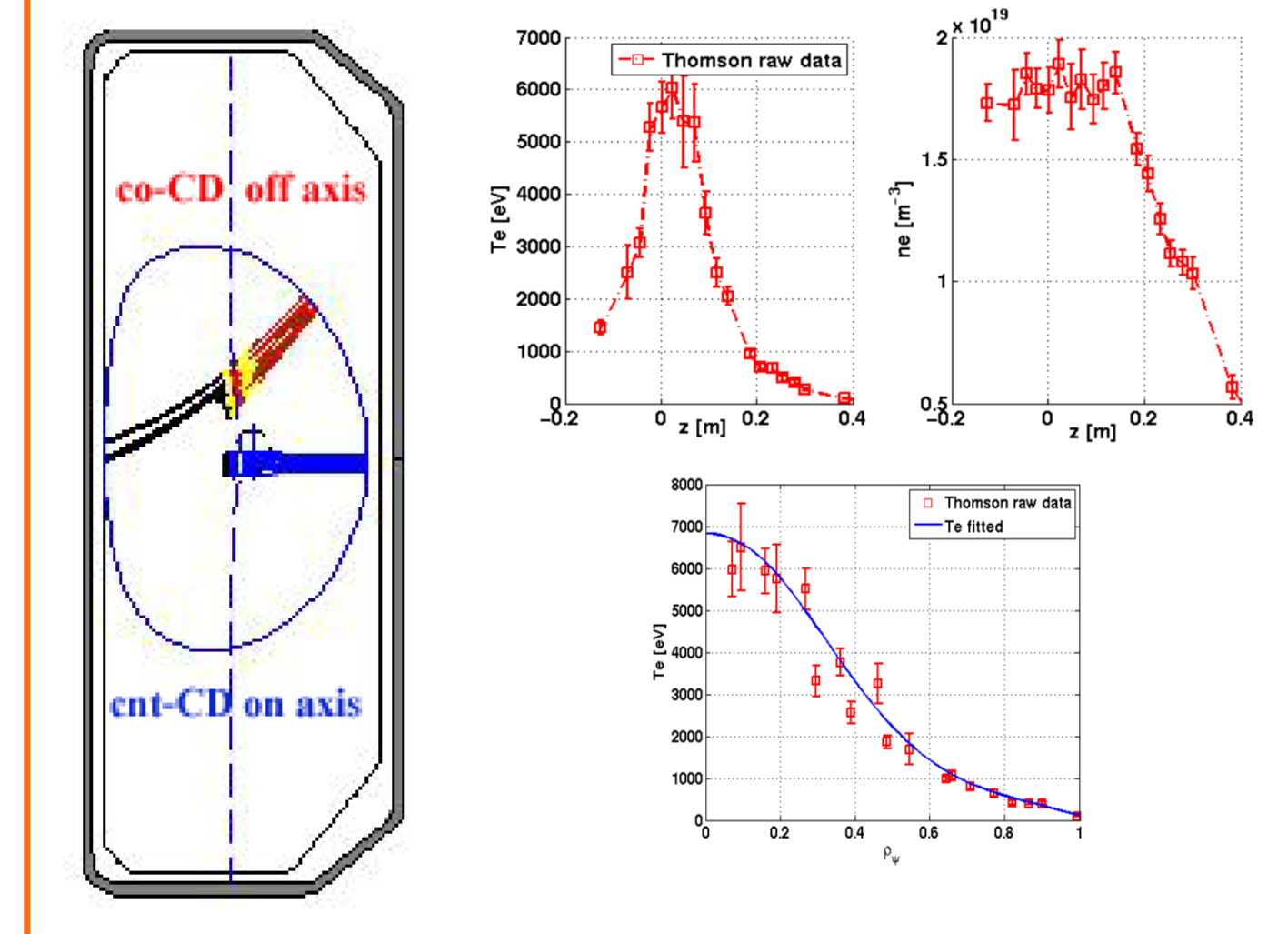
IV. Electron Internal Transport Barriers (eITB) on TCV

- eITBs formed using Electron Cyclotron Heating and Current Drive (ECH/ECCD, X2 @ 82.7 GHz) to create hollow or flat current profiles [1]
- TCV: key ingredient for eITB formation and sustainment is the degree of reverse shear [2]
- Other devices: rational q and/or the $E \times B$ shearing
- Study effect of ECH power, MHD activity on the barrier strength, v , E_r and $\omega'_{E \times B}$ profiles \rightarrow CXRS: v profiles during stationary pre-barrier, sustainment and rapid formation phases in single discharge

V. eITB targets development at $z=3$ cm on TCV

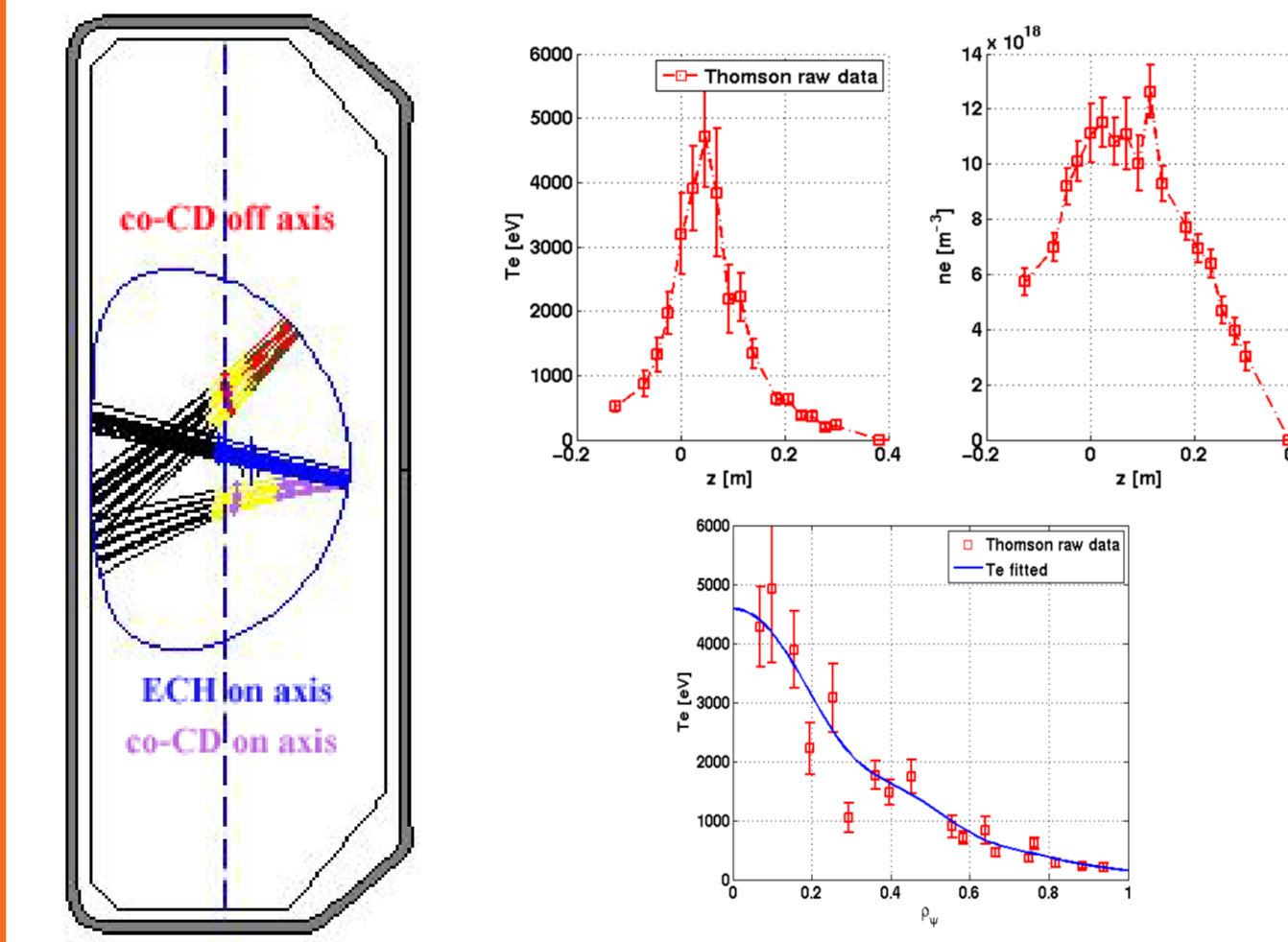
CENTRAL INTERNAL BARRIER TARGET (ICEC) [3]:

- Central cnt-CD with off-axis co-ECCD
- $\Delta z = 15$ cm, $n_e = 1.8 \times 10^{19} m^{-3}$
- $T_e = 6$ keV, $H_{RLW} = 2.9$
- Barrier in T_e but not n_e



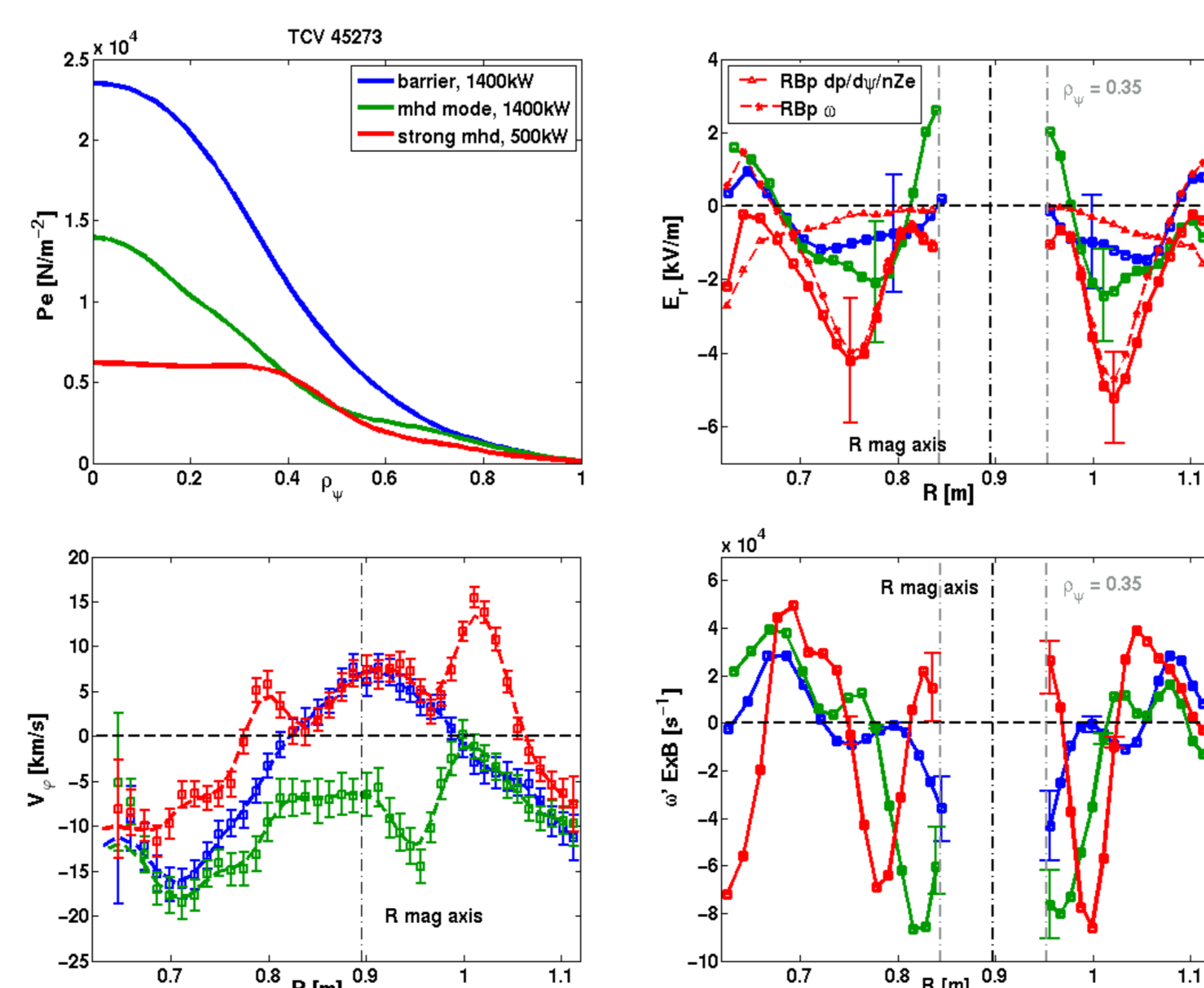
CO-ECCD eITB TARGET:

- Off-axis co-ECCD with central ECH & central co-CD (stronger and more off axis barrier than central eITB, 2300kW)
- $\Delta z = 15$ cm, $n_e = 1.8 \times 10^{19} m^{-3}$
- $T_e = 4.5$ keV, $H_{RLW} = 2.5 \rightarrow 2.8$
- RT IOH control dI_{OH}/dt
- Reduce high n_e & impurity in TCV



VI. Rotation, E_r & $E \times B$ shearing rate profiles vs MHD activity

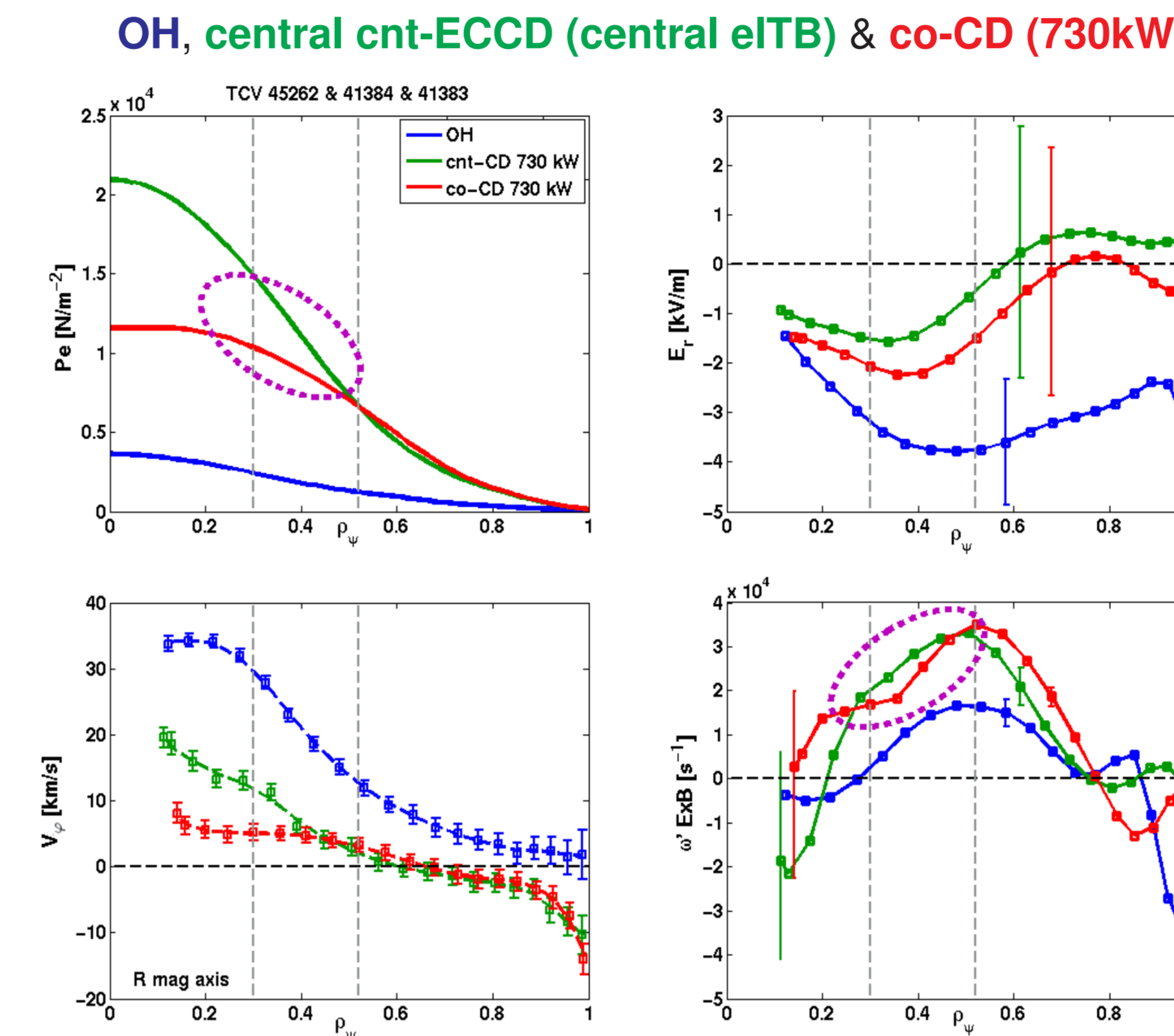
- Barrier destroyed by MHD activity: MHD mode (2,1) @ 7kHz + stronger mode
- Barrier \Rightarrow cnt-current (I_p) toroidal rotation (v_ϕ)
- MHD mode \Rightarrow rotation reversal co- I_p v_ϕ
- Strong mode \Rightarrow relaxation to cnt- I_p v_ϕ (\cong OH) and decrease in the core
- $E_r < 0$ is inward during barrier
- MHD mode causes E_r sign change in the core (outward)



- MHD activity strong effect on v_ϕ and E_r profiles
- minimum E_r (strong $\hat{\omega} R \tilde{B}_{pol}$ component) $\leftrightarrow \omega'_{E \times B} = 0$ at midradius

VII. Effect of central ECH power on the central barrier strength

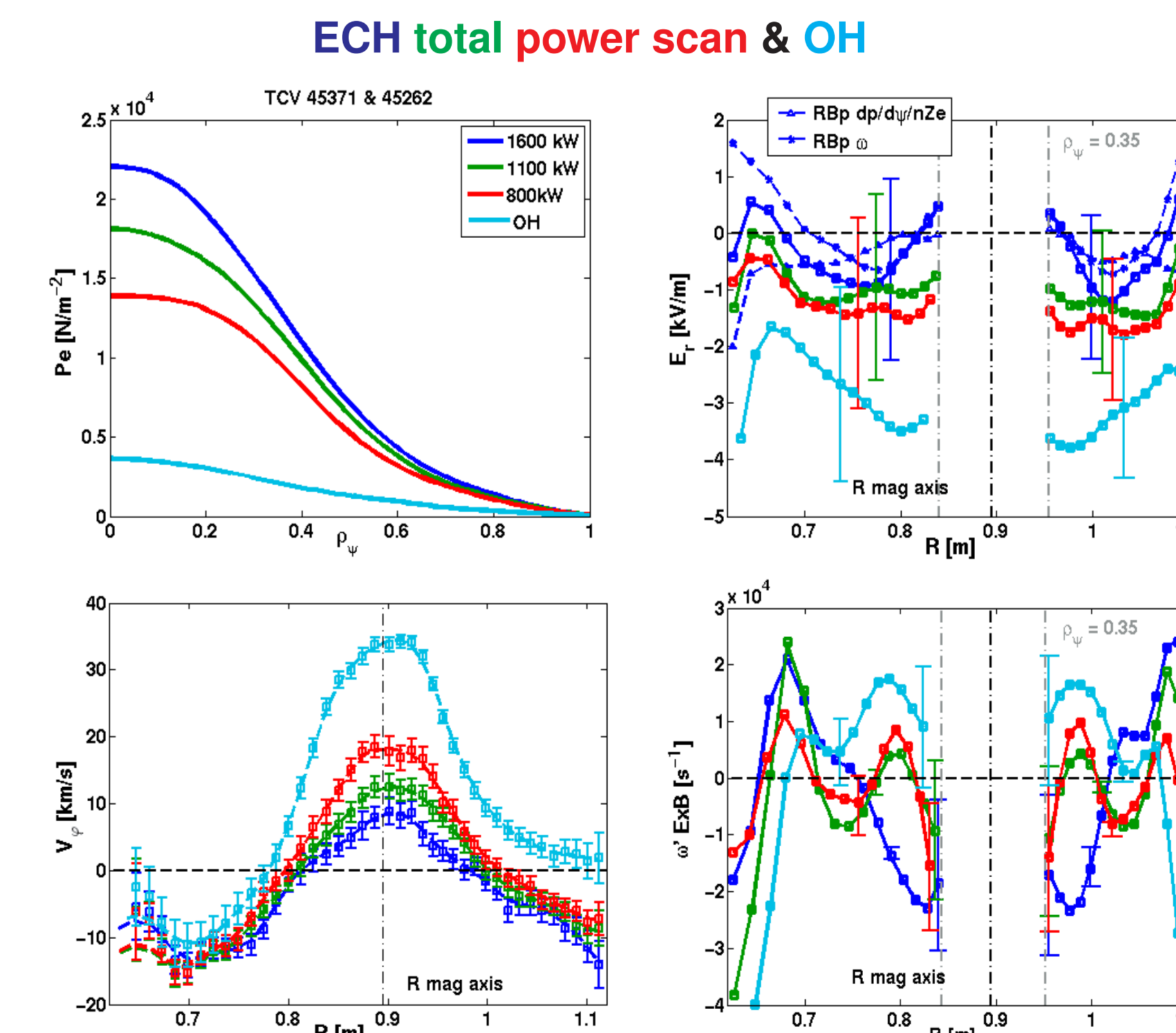
- Cnt-CD \leftrightarrow co-CD (similar to central ECH): peaked cnt- I_p v_ϕ in the core with doubled v_ϕ and p_e
- p_e increases inside $\rho_{\psi} = 0.5 \Rightarrow$ confinement improvement (barrier) [4]
- $p_e \Rightarrow$ clear difference in the electron transport!
- v_ϕ increases for $\rho_{\psi} < 0.45$
- $E_r < 0$ inward (-2 kV/m); smaller for cnt-CD than co-CD
- $E \times B$ shearing rate for cnt-CD and co-CD is similar in both cases



- $E \times B$ shearing rate not the cause of electron transport improvement
- BUT increased v_ϕ profile for central eITB may result from improved confinement

VIII. Rotation, E_r & $E \times B$ shearing rate profiles vs total power

- Central cnt- I_p v_ϕ
- Inboard-outboard v_ϕ asymmetry
- v_ϕ increases & E_r decreases when reducing the ECH power
- $E_r < 0$ inward (-[1,4]kV/m) and deeper in the core ($\hat{\omega} R \tilde{B}_{pol}$ term)



- $c_{Si} = \sqrt{\frac{T_e(500eV)}{m_p}} \cong 1.5 \times 10^5 m/s$
- $c_{Si}/R_0 \cong 1.8 \times 10^5 s^{-1}$
- TEM modes most instable in TCV eITB plasmas
- $\gamma R_0/c_{Si} = 0.4$ [5]

- $\omega'_{E \times B} \propto 10^4 s^{-1}$ smaller compare to $\gamma \propto 10^5 s^{-1}$ of TEM
- Consistent with assumed negligible effect of $\omega'_{E \times B}$ on TEM in TCV reverse shear [6,7]

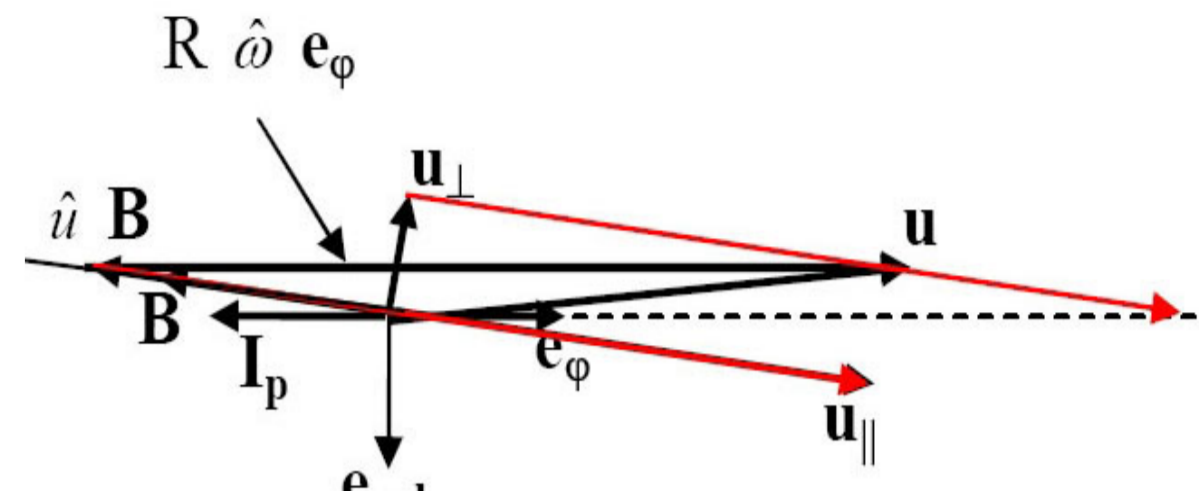
XI. Conclusions

- Effects of ECH power, co-/cnt-CD and MHD activity on the barrier strength, v , E_r and $\omega'_{E \times B}$ profiles are presented
- v_ϕ AND v_{pol} are measured with eITBs for the first time
- $E \times B$ shearing is not the cause of eITBs (confirms main role of reverse q profile for electron heating)
- $E_r \sim \nabla p_i$ and $\hat{\omega}$
- Upgraded CXRS diagnostic on TCV enables acquisition near fast events

IX. U_{pol} indirect measurement, E_r & $E \times B$ shearing rate

Tokamak Coordinate Conventions [8, 9]:

- COCOS=17
- $I_p, B_0, B_{pol} > 0$
- $\hat{\omega} > 0, \hat{u} > 0$
- $u_\phi > 0, u_{pol} < 0$



Poloidal and toroidal rotation indirect measurement ($\hat{u}(\psi), \hat{\omega}(\psi), K(\psi)$ flux functions):

$$\begin{aligned} \mathbf{u}_\sigma &= \hat{u}_\sigma(\psi) \mathbf{B} + R \hat{\omega}_\sigma(\psi) \mathbf{e}_\phi \\ u_{\sigma,\phi} &= R \hat{\omega}_\sigma(\psi) + \hat{u}_\sigma(\psi) B_\phi \\ u_{\sigma,pol} &= \hat{u}_\sigma(\psi) B_{pol} = \sigma_{B,\phi} \sigma_{I_p} \hat{u}_\sigma(\psi) \tilde{B}_{pol} \end{aligned}$$

where $\tilde{B}_{pol} = |B_{pol}|, B_\phi = F/R$. Using R_H & R_L on the same flux surface:

$$\hat{\omega}(\psi) = \frac{u_{\phi,H} R_H - u_{\phi,L} R_L}{R_L^2 - R_H^2} \quad \hat{u}(\psi) = \frac{u_{\phi,H}/R_H - u_{\phi,L}/R_L}{R_L^2 - R_H^2} \frac{R_L^2 R_H^2}{F}$$

when impurity asymmetry can not be neglected:

$$n(\psi, \theta) \hat{u}(\psi, \theta) = K(\psi) = \frac{1}{F} \left(\frac{u_{\phi,H}}{R_H} - \frac{u_{\phi,L}}{R_L} - \sigma_{B,\phi} (2\pi) \frac{e B_p T}{Z e} \frac{\partial \ln(n_H/n_L)}{\partial \psi} \right) \times \left(\frac{n_L n_H R_L^2 R_H^2}{n_L R_L^2 - n_H R_H^2} \right)$$

Radial electric field:

$$\mathbf{E} = \frac{1}{n_\sigma Z e} \nabla p_\sigma - \mathbf{u}_\sigma \times \mathbf{B} \quad \frac{\mathbf{E} \cdot \nabla \psi}{|\nabla \psi|} = \left[\frac{1}{n_\sigma Z e} \frac{dp_\sigma(\psi)}{d\psi} + \hat{\omega}_\sigma(\psi) \frac{\sigma_{B_p}}{(2\pi) e B_p} \right] (2\pi) e B_p R \tilde{B}_{pol}$$

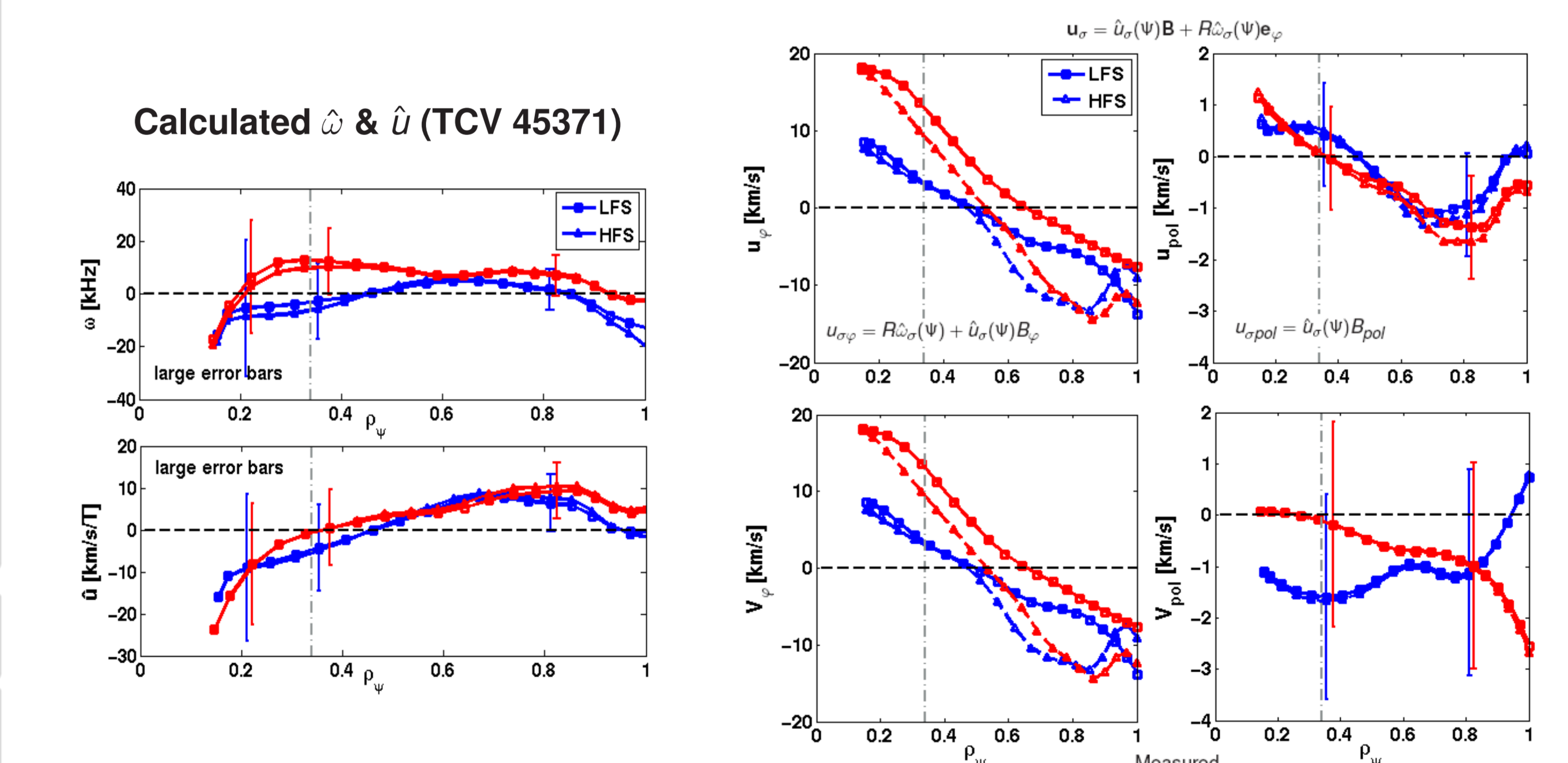
$$E_r = \left[\frac{(2\pi) e B_p}{n_\sigma Z e} \frac{dp_\sigma}{d|\psi - \psi_{axis}|} + \hat{\omega}_\sigma(\psi) \sigma_{I_p} \right] R \tilde{B}_{pol} \quad E_r(\rho_\psi = 0) = 0$$

where $d\psi = \sigma_{B,\phi} \sigma_{I_p} d|\psi - \psi_{axis}|$

$E \times B$ shearing rate [10]:

$$\omega'_{E \times B} = \frac{r}{q_s B_0} \frac{d}{dr} \left(\frac{q_s E_r}{r} \right)$$

X. Agreement between measured v_ϕ, v_{pol} and indirect u_ϕ, u_{pol}



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This work was partly supported by the Swiss National Science Foundation.